

DATA SHEET

**DPS-532-B**/5~15mJ

## **HIGH ENERGY DIODE** PUMPED ALL-SOLID-STATE **Q-SWITCHED LASER**

High energy diode pumped all solid state Q-switched laser at 532nm has the features of high single pulse energy, short pulse duration, and high peak power, which is widely used in LIBS, LIF, ICP-MS, LCD repair, scientific research, military, and so on.









## SPECIFICATIONS

Wavelength (nm)	532±l
Operating mode	Q-switched:Electro-optic Modulation
Single pulse energy (mJ)	5~15
Pulse duration (ns)	<10
Rep. rate (Hz)	1~10, EXT (adjustable)
Energy stability(rms)	<3%
Beam divergence, full angle (mrad)	~1
Beam diameter (mm)	3
Warm-up time (minutes)	<15
Beam height from base plate (mm)	35
Cooled method	Air cooled
Operating temperature (°C)	15~30
Power supply (220V AC)	PSU-DPS-B
Expected lifetime (pluses)	109
Warranty period	1 year







